

NTB0101A

Auto direction sensing dual supply

Rev. 1 — 14 July 2015

Product data sheet

1. General description

The NTB0101A is a 1-bit, dual supply translating transceiver with auto direction sensing, that enables bidirectional voltage level translation. It consists of two 1-bit I/O ports (A and B), one output enable input ($\overline{\text{OE}}$) and two supply pins ($V_{\text{CC(A)}}$ and $V_{\text{CC(B)}}$). $V_{\text{CC(A)}}$ can be supplied at any voltage between 1.2 V and 3.6 V. $V_{\text{CC(B)}}$ can be supplied at any voltage between 1.65 V and 5.5 V. This flexibility allows translation between any of the low voltage nodes (1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V and 5.0 V).

Pins A and $\overline{\text{OE}}$ are referenced to $V_{\text{CC(A)}}$ and pin B is referenced to $V_{\text{CC(B)}}$. A HIGH level at pin $\overline{\text{OE}}$ causes the outputs to assume a high-impedance OFF-state. This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing damage of the device due to backflow current, when it is powered down.

2. Features and benefits

- Wide supply voltage range:
 - ◆ $V_{\text{CC(A)}}$: 1.2 V to 3.6 V and $V_{\text{CC(B)}}$: 1.65 V to 5.5 V
- I_{OFF} circuitry provides partial power-down mode operation
- Inputs accept voltages up to 5.5 V
- ESD protection:
 - ◆ HBM JESD22-A114E Class 2 exceeds 2500 V for port A
 - ◆ HBM JESD22-A114E Class 3B exceeds 15000 V for port B
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101E exceeds 1500 V
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$



3. Ordering information

Table 1. Ordering information

| Type number | Package | | |
|-------------|---------|--|---------|
| | Name | Description | Version |
| NTB0101AGW | SC-88 | plastic surface-mounted package; 6 leads | SOT363 |

4. Marking

Table 2. Marking codes

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| NTB0101AGW | tL |

[1] The pin 1 indicator is on the lower left corner of the device, below the marking code.

5. Functional diagram

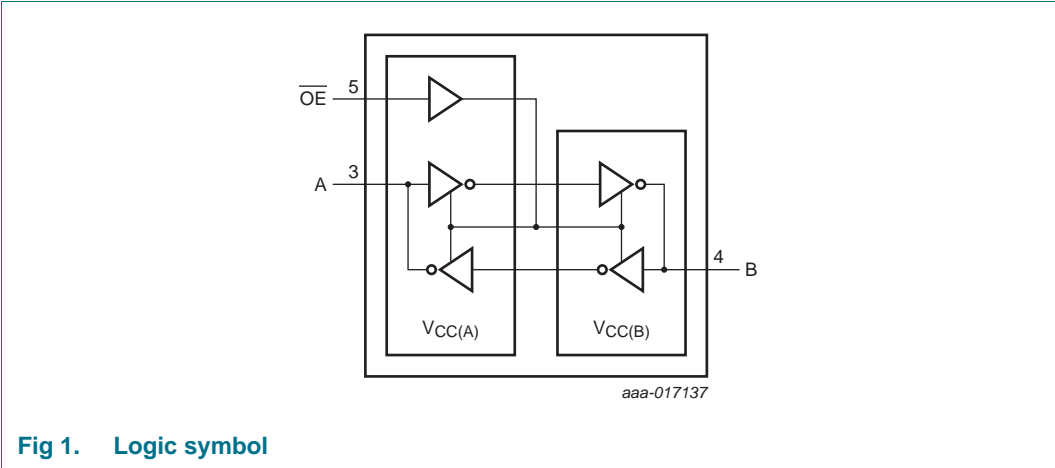


Fig 1. Logic symbol

6. Pinning information

6.1 Pinning

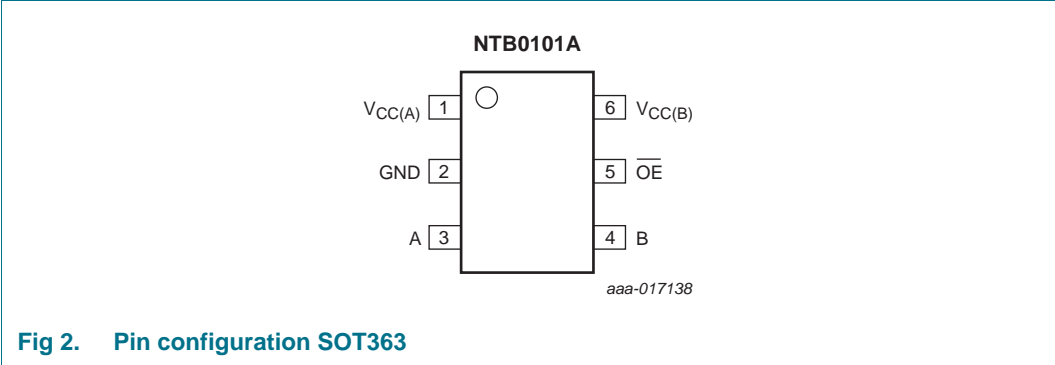


Fig 2. Pin configuration SOT363

6.2 Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|-----------------|-----|--|
| $V_{CC(A)}$ | 1 | supply voltage A |
| GND | 2 | ground (0 V) |
| A | 3 | data input or output (referenced to $V_{CC(A)}$) |
| B | 4 | data input or output (referenced to $V_{CC(B)}$) |
| \overline{OE} | 5 | output enable input (active LOW; referenced to $V_{CC(A)}$) |
| $V_{CC(B)}$ | 6 | supply voltage B |

7. Functional description

Table 4. Function table^[1]

| Supply voltage | | Input | Input/output | |
|----------------------|--------------------|-----------------|-----------------|-----------------|
| $V_{CC(A)}$ | $V_{CC(B)}$ | \overline{OE} | A | B |
| 1.2 V to $V_{CC(B)}$ | 1.65 V to 5.5 V | H | Z | Z |
| 1.2 V to $V_{CC(B)}$ | 1.65 V to 5.5 V | L | input or output | output or input |
| GND ^[2] | GND ^[2] | X | Z | Z |

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

[2] When either $V_{CC(A)}$ or $V_{CC(B)}$ is at GND level, the device goes into power-down mode.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-------------|-------------------------|-------------------------------|------|-----------------|------|
| $V_{CC(A)}$ | supply voltage A | | -0.5 | +6.5 | V |
| $V_{CC(B)}$ | supply voltage B | | -0.5 | +6.5 | V |
| V_I | input voltage | | -0.5 | +6.5 | V |
| V_O | output voltage | active mode | -0.5 | $V_{CCO} + 0.5$ | V |
| | | power-down or 3-state mode | -0.5 | +6.5 | V |
| I_{IK} | input clamping current | $V_I < 0$ V | -50 | - | mA |
| I_{OK} | output clamping current | $V_O < 0$ V | -50 | - | mA |
| I_O | output current | $V_O = 0$ V to V_{CCO} | - | ± 50 | mA |
| I_{CC} | supply current | $I_{CC(A)}$ or $I_{CC(B)}$ | - | 100 | mA |
| I_{GND} | ground current | | -100 | - | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P_{tot} | total power dissipation | $T_{amb} = -40$ °C to +125 °C | - | 250 | mW |

[1] If the input and output current ratings are observed, the minimum input and minimum output voltage ratings may be exceeded.

[2] V_{CCO} is the supply voltage associated with the output.

[3] $V_{CCO} + 0.5$ V should not exceed 6.5 V.

[4] Above 87.5 °C, the value of P_{tot} derates linearly with 4.0 mW/K.

9. Recommended operating conditions

Table 6. Operating conditions^{[1][2]}

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---------------------|-------------------------------------|---|------|------|------|
| $V_{CC(A)}$ | supply voltage A | | 1.2 | 3.6 | V |
| $V_{CC(B)}$ | supply voltage B | | 1.65 | 5.5 | V |
| V_I | input voltage | | 0 | 5.5 | V |
| V_O | output voltage | power-down or 3-state mode; $V_{CC(A)} = 1.2\text{ V to }3.6\text{ V};$ $V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$ | | | |
| | | port A | 0 | 3.6 | V |
| | | port B | 0 | 5.5 | V |
| T_{amb} | ambient temperature | | -40 | +125 | °C |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC(A)} = 1.2\text{ V to }3.6\text{ V};$ $V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$ | - | 40 | ns/V |

[1] The A and B sides of an unused I/O pair must be held in the same state, both at V_{CCI} or GND.

[2] $V_{CC(A)}$ must be less than or equal to $V_{CC(B)}$.

10. Static characteristics

Table 7. Typical static characteristics

At recommended operating conditions; $T_{amb} = 25\text{ °C}$; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|---------------------------|--|-----|------|---------|---------------|
| V_{OH} | HIGH-level output voltage | port A; $V_{CC(A)} = 1.2\text{ V}; I_O = -20\text{ }\mu\text{A}$ | - | 1.1 | - | V |
| V_{OL} | LOW-level output voltage | port A; $V_{CC(A)} = 1.2\text{ V}; I_O = 20\text{ }\mu\text{A}$ | - | 0.09 | - | V |
| I_I | input leakage current | \overline{OE} input; $V_I = 0\text{ V to }3.6\text{ V}; V_{CC(A)} = 1.2\text{ V to }3.6\text{ V};$ $V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$ | - | - | ± 1 | μA |
| I_{OZ} | OFF-state output current | port A or B; $V_O = 0\text{ V to }V_{CCO}; V_{CC(A)} = 1.2\text{ V to }3.6\text{ V};$ [1] $V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$ | - | - | ± 1 | μA |
| I_{OFF} | power-off leakage current | port A; V_I or $V_O = 0\text{ V to }3.6\text{ V};$ $V_{CC(A)} = 0\text{ V}; V_{CC(B)} = 0\text{ V to }5.5\text{ V}$ | - | - | ± 1 | μA |
| | | port B; V_I or $V_O = 0\text{ V to }5.5\text{ V};$ $V_{CC(B)} = 0\text{ V}; V_{CC(A)} = 0\text{ V to }3.6\text{ V}$ | - | - | ± 1 | μA |
| C_I | input capacitance | \overline{OE} input; $V_{CC(A)} = 1.2\text{ V to }3.6\text{ V}; V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$ | - | 1.0 | - | pF |
| $C_{I/O}$ | input/output capacitance | port A; $V_{CC(A)} = 1.2\text{ V to }3.6\text{ V}; V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$ | - | 4.0 | - | pF |
| | | port B; $V_{CC(A)} = 1.2\text{ V to }3.6\text{ V}; V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$ | - | 7.5 | - | pF |

[1] V_{CCO} is the supply voltage associated with the output.

Table 8. Typical supply currentAt recommended operating conditions; $T_{amb} = 25\text{ }^{\circ}\text{C}$; voltages are referenced to GND (ground = 0 V).

| V _{CC(A)} | V _{CC(B)} | | | | | | | | Unit |
|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|------|
| | 1.8 V | | 2.5 V | | 3.3 V | | 5.0 V | | |
| | I _{CC(A)} | I _{CC(B)} | I _{CC(A)} | I _{CC(B)} | I _{CC(A)} | I _{CC(B)} | I _{CC(A)} | I _{CC(B)} | |
| 1.2 V | 10 | 10 | 10 | 10 | 10 | 20 | 10 | 1050 | nA |
| 1.5 V | 10 | 10 | 10 | 10 | 10 | 10 | 10 | 650 | nA |
| 1.8 V | 10 | 10 | 10 | 10 | 10 | 10 | 10 | 350 | nA |
| 2.5 V | - | - | 10 | 10 | 10 | 10 | 10 | 40 | nA |
| 3.3 V | - | - | - | - | 10 | 10 | 10 | 10 | nA |

Table 9. Static characteristics^[1]

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | $T_{amb} = -40\text{ }^{\circ}\text{C to } +85\text{ }^{\circ}\text{C}$ | | $T_{amb} = -40\text{ }^{\circ}\text{C to } +125\text{ }^{\circ}\text{C}$ | | Unit |
|-----------|---------------------------|---|---|---------------|--|---------------|---------------|
| | | | Min | Max | Min | Max | |
| V_{IH} | HIGH-level input voltage | port A or port B and \overline{OE} input; $V_{CC(A)} = 1.2\text{ V to } 3.6\text{ V}$; $V_{CC(B)} = 1.65\text{ V to } 5.5\text{ V}$ | $0.65V_{CCI}$ | - | $0.65V_{CCI}$ | - | V |
| V_{IL} | LOW-level input voltage | port A or port B and \overline{OE} input; $V_{CC(A)} = 1.2\text{ V to } 3.6\text{ V}$; $V_{CC(B)} = 1.65\text{ V to } 5.5\text{ V}$ | - | $0.35V_{CCI}$ | - | $0.35V_{CCI}$ | V |
| V_{OH} | HIGH-level output voltage | $I_O = -20\text{ }\mu\text{A}$ | | | | | |
| | | port A; $V_{CC(A)} = 1.4\text{ V to } 3.6\text{ V}$ | $V_{CCO} - 0.4$ | - | $V_{CCO} - 0.4$ | - | V |
| | | port B; $V_{CC(B)} = 1.65\text{ V to } 5.5\text{ V}$ | $V_{CCO} - 0.4$ | - | $V_{CCO} - 0.4$ | - | V |
| V_{OL} | LOW-level output voltage | $I_O = 20\text{ }\mu\text{A}$ | | | | | |
| | | port A; $V_{CC(A)} = 1.4\text{ V to } 3.6\text{ V}$ | - | 0.4 | - | 0.4 | V |
| | | port B; $V_{CC(B)} = 1.65\text{ V to } 5.5\text{ V}$ | - | 0.4 | - | 0.4 | V |
| I_I | input leakage current | \overline{OE} input; $V_I = 0\text{ V to } 3.6\text{ V}$; $V_{CC(A)} = 1.2\text{ V to } 3.6\text{ V}$; $V_{CC(B)} = 1.65\text{ V to } 5.5\text{ V}$ | - | ± 2 | - | ± 5 | μA |
| I_{OZ} | OFF-state output current | port A or port B; $V_O = 0\text{ V or } V_{CCO}$; $V_{CC(A)} = 1.2\text{ V to } 3.6\text{ V}$; $V_{CC(B)} = 1.65\text{ V to } 5.5\text{ V}$ | - | ± 2 | - | ± 10 | μA |
| I_{OFF} | power-off leakage current | port A; V_I or $V_O = 0\text{ V to } 3.6\text{ V}$; $V_{CC(A)} = 0\text{ V}$; $V_{CC(B)} = 0\text{ V to } 5.5\text{ V}$ | - | ± 2 | - | ± 10 | μA |
| | | port B; V_I or $V_O = 0\text{ V to } 5.5\text{ V}$; $V_{CC(B)} = 0\text{ V}$; $V_{CC(A)} = 0\text{ V to } 3.6\text{ V}$ | - | ± 2 | - | ± 10 | μA |

Table 9. Static characteristics^[1] ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | T _{amb} = -40 °C to +85 °C | | T _{amb} = -40 °C to +125 °C | | Unit |
|-----------------|----------------|--|-------------------------------------|-----|--------------------------------------|-----|------|
| | | | Min | Max | Min | Max | |
| I _{CC} | supply current | V _I = 0 V or V _{CCI} ; I _O = 0 A | | | | | |
| | | I _{CC(A)} | | | | | |
| | | $\overline{\text{OE}}$ = HIGH; V _{CC(A)} = 1.4 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V | - | 3 | - | 15 | μA |
| | | $\overline{\text{OE}}$ = LOW; V _{CC(A)} = 1.4 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V | - | 3 | - | 20 | μA |
| | | V _{CC(A)} = 3.6 V; V _{CC(B)} = 0 V | - | 2 | - | 15 | μA |
| | | V _{CC(A)} = 0 V; V _{CC(B)} = 5.5 V | - | -2 | - | -15 | μA |
| | | I _{CC(B)} | | | | | |
| | | $\overline{\text{OE}}$ = HIGH; V _{CC(A)} = 1.4 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V | - | 5 | - | 15 | μA |
| | | $\overline{\text{OE}}$ = LOW; V _{CC(A)} = 1.4 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V | - | 5 | - | 20 | μA |
| | | V _{CC(A)} = 3.6 V; V _{CC(B)} = 0 V | - | -2 | - | -15 | μA |
| | | V _{CC(A)} = 0 V; V _{CC(B)} = 5.5 V | - | 2 | - | 15 | μA |
| | | I _{CC(A)} + I _{CC(B)} | | | | | |
| | | V _{CC(A)} = 1.4 V to 3.6 V; V _{CC(B)} = 1.65 V to 5.5 V | - | 8 | - | 40 | μA |

[1] V_{CCI} is the supply voltage associated with the input and V_{CCO} is the supply voltage associated with the output.

11. Dynamic characteristics

Table 10. Typical dynamic characteristics^[1]Voltages are referenced to GND (ground = 0 V); typical values are measured with V_{CC(A)} = 1.2 V and T_{amb} = 25 °C; for test circuit, see [Figure 5](#); for waveforms, see [Figure 3](#) and [Figure 4](#).

| Symbol | Parameter | Conditions | V _{CC(B)} | | | | Unit |
|-------------------|-------------------|--|--------------------|-------|-------|-------|--------|
| | | | 1.8 V | 2.5 V | 3.3 V | 5.0 V | |
| t _{pd} | propagation delay | A to B | 5.9 | 4.8 | 4.4 | 4.2 | ns |
| | | B to A | 5.6 | 4.8 | 4.5 | 4.4 | ns |
| t _{en} | enable time | $\overline{\text{OE}}$ to A, B | 0.5 | 0.5 | 0.5 | 0.5 | μs |
| t _{dis} | disable time | $\overline{\text{OE}}$ to A; no external load ^[2] | 6.9 | 6.9 | 6.9 | 6.9 | ns |
| | | $\overline{\text{OE}}$ to B; no external load ^[2] | 9.5 | 8.6 | 8.5 | 8.0 | ns |
| | | $\overline{\text{OE}}$ to A | 81 | 69 | 83 | 68 | ns |
| | | $\overline{\text{OE}}$ to B | 81 | 69 | 83 | 68 | ns |
| t _t | transition time | port A | 4.0 | 4.0 | 4.1 | 4.1 | ns |
| | | port B | 2.6 | 2.0 | 1.7 | 1.4 | ns |
| t _W | pulse width | data inputs | 15 | 13 | 13 | 13 | ns |
| f _{data} | data rate | | 70 | 80 | 80 | 80 | Mbit/s |

- [1] t_{pd} is the same as t_{PLH} and t_{PHL} .
 t_{en} is the same as t_{PZL} and t_{PZH} .
 t_{dis} is the same as t_{PLZ} and t_{PHZ} .
 t_t is the same as t_{THL} and t_{TLH} .
- [2] Delay between \overline{OE} going HIGH and when the outputs are disabled.

Table 11. Dynamic characteristics for temperature range $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ ^[1]

Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 5](#); for waveforms, see [Figure 3](#) and [Figure 4](#).

| Symbol | Parameter | Conditions | V _{CC(B)} | | | | | | | | Unit |
|-------------------------------------|-------------------|---|--------------------|------|---------------|------|---------------|------|---------------|------|--------|
| | | | 1.8 V ± 0.15 V | | 2.5 V ± 0.2 V | | 3.3 V ± 0.3 V | | 5.0 V ± 0.5 V | | |
| | | | Min | Max | Min | Max | Min | Max | Min | Max | |
| V _{CC(A)} = 1.5 V ± 0.1 V | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.4 | 12.9 | 1.2 | 10.1 | 1.1 | 10.0 | 0.8 | 9.9 | ns |
| | | B to A | 0.9 | 14.2 | 0.7 | 12.0 | 0.4 | 11.7 | 0.3 | 13.7 | ns |
| t _{en} | enable time | OE to A, B | - | 1.0 | - | 1.0 | - | 1.0 | - | 1.0 | μs |
| t _{dis} | disable time | OE to A; no external load [2] | 1.0 | 11.9 | 1.0 | 11.9 | 1.0 | 11.9 | 1.0 | 11.9 | ns |
| | | OE to B; no external load [2] | 1.0 | 16.9 | 1.0 | 15.2 | 1.0 | 14.1 | 1.0 | 13.8 | ns |
| | | OE to A | - | 320 | - | 260 | - | 260 | - | 280 | ns |
| | | OE to B | - | 200 | - | 200 | - | 200 | - | 200 | ns |
| t _t | transition time | port A | 0.9 | 5.1 | 0.9 | 5.1 | 0.9 | 5.1 | 0.9 | 5.1 | ns |
| | | port B | 0.9 | 4.7 | 0.6 | 3.2 | 0.5 | 2.5 | 0.4 | 2.7 | ns |
| t _W | pulse width | data inputs | 25 | - | 25 | - | 25 | - | 25 | - | ns |
| f _{data} | data rate | | - | 40 | - | 40 | - | 40 | - | 40 | Mbit/s |
| V _{CC(A)} = 1.8 V ± 0.15 V | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.6 | 11.0 | 1.4 | 7.7 | 1.3 | 6.8 | 1.2 | 6.5 | ns |
| | | B to A | 1.5 | 12.0 | 1.3 | 8.4 | 1.0 | 7.6 | 0.9 | 7.1 | ns |
| t _{en} | enable time | OE to A, B | - | 1.0 | - | 1.0 | - | 1.0 | - | 1.0 | μs |
| t _{dis} | disable time | OE to A; no external load [2] | 1.0 | 11.0 | 1.0 | 11.0 | 1.0 | 11.0 | 1.0 | 11.0 | ns |
| | | OE to B; no external load [2] | 1.0 | 15.4 | 1.0 | 13.5 | 1.0 | 12.4 | 1.0 | 12.1 | ns |
| | | OE to A | - | 260 | - | 230 | - | 230 | - | 230 | ns |
| | | OE to B | - | 200 | - | 200 | - | 200 | - | 200 | ns |
| t _t | transition time | port A | 0.8 | 4.1 | 0.8 | 4.1 | 0.8 | 4.1 | 0.8 | 4.1 | ns |
| | | port B | 0.9 | 4.7 | 0.6 | 3.2 | 0.5 | 2.5 | 0.4 | 2.7 | ns |
| t _W | pulse width | data inputs | 20 | - | 17 | - | 17 | - | 17 | - | ns |
| f _{data} | data rate | | - | 49 | - | 60 | - | 60 | - | 60 | Mbit/s |
| V _{CC(A)} = 2.5 V ± 0.2 V | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | - | - | 1.1 | 6.3 | 1.0 | 5.2 | 0.9 | 4.7 | ns |
| | | B to A | - | - | 1.2 | 6.6 | 1.1 | 5.1 | 0.9 | 4.4 | ns |
| t _{en} | enable time | OE to A, B | - | - | - | 1.0 | - | 1.0 | - | 1.0 | μs |

Table 11. Dynamic characteristics for temperature range -40°C to $+85^{\circ}\text{C}$ ^[1] ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 5](#); for waveforms, see [Figure 3](#) and [Figure 4](#).

| Symbol | Parameter | Conditions | V _{CC(B)} | | | | | | | | Unit |
|------------------------------------|-------------------|---|--------------------|-----|---------------|------|---------------|------|---------------|------|--------|
| | | | 1.8 V ± 0.15 V | | 2.5 V ± 0.2 V | | 3.3 V ± 0.3 V | | 5.0 V ± 0.5 V | | |
| | | | Min | Max | Min | Max | Min | Max | Min | Max | |
| t _{dis} | disable time | $\overline{\text{OE}}$ to A; no external load [2] | - | - | 1.0 | 9.2 | 1.0 | 9.2 | 1.0 | 9.2 | ns |
| | | $\overline{\text{OE}}$ to B; no external load [2] | - | - | 1.0 | 11.9 | 1.0 | 10.7 | 1.0 | 10.2 | ns |
| | | $\overline{\text{OE}}$ to A | - | - | - | 200 | - | 200 | - | 200 | ns |
| | | $\overline{\text{OE}}$ to B | - | - | - | 200 | - | 200 | - | 200 | ns |
| t _t | transition time | port A | - | - | 0.7 | 3.0 | 0.7 | 3.0 | 0.7 | 3.0 | ns |
| | | port B | - | - | 0.7 | 3.2 | 0.5 | 2.5 | 0.4 | 2.7 | ns |
| t _W | pulse width | data inputs | - | - | 12 | - | 10 | - | 10 | - | ns |
| f _{data} | data rate | | - | - | - | 85 | - | 100 | - | 100 | Mbit/s |
| V _{CC(A)} = 3.3 V ± 0.3 V | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | - | - | - | - | 0.9 | 4.7 | 0.8 | 4.0 | ns |
| | | B to A | - | - | - | - | 1.0 | 4.9 | 0.9 | 3.8 | ns |
| t _{en} | enable time | $\overline{\text{OE}}$ to A, B | - | - | - | - | - | 1.0 | - | 1.0 | μs |
| t _{dis} | disable time | $\overline{\text{OE}}$ to A; no external load [2] | - | - | - | - | 1.0 | 9.2 | 1.0 | 9.2 | ns |
| | | $\overline{\text{OE}}$ to B; no external load [2] | - | - | - | - | 1.0 | 10.1 | 1.0 | 9.6 | ns |
| | | $\overline{\text{OE}}$ to A | - | - | - | - | - | 260 | - | 260 | ns |
| | | $\overline{\text{OE}}$ to B | - | - | - | - | - | 200 | - | 200 | ns |
| t _t | transition time | port A | - | - | - | - | 0.7 | 2.5 | 0.7 | 2.5 | ns |
| | | port B | - | - | - | - | 0.5 | 2.5 | 0.4 | 2.7 | ns |
| t _W | pulse width | data inputs | - | - | - | - | 10 | - | 10 | - | ns |
| f _{data} | data rate | | - | - | - | - | - | 100 | - | 100 | Mbit/s |

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

t_{en} is the same as t_{PZL} and t_{PZH} .

t_{dis} is the same as t_{PLZ} and t_{PHZ} .

t_t is the same as t_{THL} and t_{TLH} .

[2] Delay between $\overline{\text{OE}}$ going HIGH and when the outputs are disabled.

Table 12. Dynamic characteristics for temperature range -40°C to $+125^{\circ}\text{C}$ ^[1]

Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 5](#); for waveforms, see [Figure 3](#) and [Figure 4](#).

| Symbol | Parameter | Conditions | V _{CC(B)} | | | | | | | | Unit |
|------------------------------------|-------------------|------------|--------------------|------|---------------|------|---------------|------|---------------|------|------|
| | | | 1.8 V ± 0.15 V | | 2.5 V ± 0.2 V | | 3.3 V ± 0.3 V | | 5.0 V ± 0.5 V | | |
| | | | Min | Max | Min | Max | Min | Max | Min | Max | |
| V _{CC(A)} = 1.5 V ± 0.1 V | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.4 | 15.9 | 1.2 | 13.1 | 1.1 | 13.0 | 0.8 | 12.9 | ns |
| | | B to A | 0.9 | 17.2 | 0.7 | 15.0 | 0.4 | 14.7 | 0.3 | 16.7 | ns |
| t _{en} | enable time | OE to A, B | - | 1.0 | - | 1.0 | - | 1.0 | - | 1.0 | µs |

Table 12. Dynamic characteristics for temperature range -40°C to $+125^{\circ}\text{C}$ [\[1\]](#) ...continuedVoltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 5](#); for waveforms, see [Figure 3](#) and [Figure 4](#).

| Symbol | Parameter | Conditions | V _{CC(B)} | | | | | | | | Unit |
|-------------------------------------|-------------------|---|--------------------|------|---------------|------|---------------|------|---------------|------|--------|
| | | | 1.8 V ± 0.15 V | | 2.5 V ± 0.2 V | | 3.3 V ± 0.3 V | | 5.0 V ± 0.5 V | | |
| | | | Min | Max | Min | Max | Min | Max | Min | Max | |
| t _{dis} | disable time | $\overline{\text{OE}}$ to A; no external load [2] | 1.0 | 12.5 | 1.0 | 12.5 | 1.0 | 12.5 | 1.0 | 12.5 | ns |
| | | $\overline{\text{OE}}$ to B; no external load [2] | 1.0 | 18.1 | 1.0 | 16.2 | 1.0 | 14.9 | 1.0 | 14.6 | ns |
| | | $\overline{\text{OE}}$ to A | - | 340 | - | 280 | - | 280 | - | 300 | ns |
| | | $\overline{\text{OE}}$ to B | - | 220 | - | 220 | - | 220 | - | 220 | ns |
| t _t | transition time | port A | 0.9 | 7.1 | 0.9 | 7.1 | 0.9 | 7.1 | 0.9 | 7.1 | ns |
| | | port B | 0.9 | 6.5 | 0.6 | 5.2 | 0.5 | 4.8 | 0.4 | 4.7 | ns |
| t _W | pulse width | data inputs | 25 | - | 25 | - | 25 | - | 25 | - | ns |
| f _{data} | data rate | | - | 40 | - | 40 | - | 40 | - | 40 | Mbit/s |
| V _{CC(A)} = 1.8 V ± 0.15 V | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | 1.6 | 14.0 | 1.4 | 10.7 | 1.3 | 9.8 | 1.2 | 9.5 | ns |
| | | B to A | 1.5 | 15.0 | 1.3 | 11.4 | 1.0 | 10.6 | 0.9 | 10.1 | ns |
| t _{en} | enable time | $\overline{\text{OE}}$ to A, B | - | 1.0 | - | 1.0 | - | 1.0 | - | 1.0 | μs |
| t _{dis} | disable time | $\overline{\text{OE}}$ to A; no external load [2] | 1.0 | 11.5 | 1.0 | 11.5 | 1.0 | 11.5 | 1.0 | 11.5 | ns |
| | | $\overline{\text{OE}}$ to B; no external load [2] | 1.0 | 16.5 | 1.0 | 14.5 | 1.0 | 13.3 | 1.0 | 12.7 | ns |
| | | $\overline{\text{OE}}$ to A | - | 280 | - | 250 | - | 250 | - | 250 | ns |
| | | $\overline{\text{OE}}$ to B | - | 220 | - | 220 | - | 220 | - | 220 | ns |
| t _t | transition time | port A | 0.8 | 6.2 | 0.8 | 6.1 | 0.8 | 6.1 | 0.8 | 6.1 | ns |
| | | port B | 0.9 | 5.8 | 0.6 | 5.2 | 0.5 | 4.8 | 0.4 | 4.7 | ns |
| t _W | pulse width | data inputs | 22 | - | 19 | - | 19 | - | 19 | - | ns |
| f _{data} | data rate | | - | 45 | - | 55 | - | 55 | - | 55 | Mbit/s |
| V _{CC(A)} = 2.5 V ± 0.2 V | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | - | - | 1.1 | 9.3 | 1.0 | 8.2 | 0.9 | 7.7 | ns |
| | | B to A | - | - | 1.2 | 9.6 | 1.1 | 8.1 | 0.9 | 7.4 | ns |
| t _{en} | enable time | $\overline{\text{OE}}$ to A, B | - | - | - | 1.0 | - | 1.0 | - | 1.0 | μs |
| t _{dis} | disable time | $\overline{\text{OE}}$ to A; no external load [2] | - | - | 1.0 | 9.6 | 1.0 | 9.6 | 1.0 | 9.6 | ns |
| | | $\overline{\text{OE}}$ to B; no external load [2] | - | - | 1.0 | 12.6 | 1.0 | 11.4 | 1.0 | 10.8 | ns |
| | | $\overline{\text{OE}}$ to A | - | - | - | 220 | - | 220 | - | 220 | ns |
| | | $\overline{\text{OE}}$ to B | - | - | - | 220 | - | 220 | - | 220 | ns |
| t _t | transition time | port A | - | - | 0.7 | 5.0 | 0.7 | 5.0 | 0.7 | 5.0 | ns |
| | | port B | - | - | 0.7 | 4.6 | 0.5 | 4.8 | 0.4 | 4.7 | ns |
| t _W | pulse width | data inputs | - | - | 14 | - | 13 | - | 10 | - | ns |
| f _{data} | data rate | | - | - | - | 75 | - | 80 | - | 100 | Mbit/s |
| V _{CC(A)} = 3.3 V ± 0.3 V | | | | | | | | | | | |
| t _{pd} | propagation delay | A to B | - | - | - | - | 0.9 | 7.7 | 0.8 | 7.0 | ns |
| | | B to A | - | - | - | - | 1.0 | 7.9 | 0.9 | 6.8 | ns |
| t _{en} | enable time | $\overline{\text{OE}}$ to A, B | - | - | - | - | - | 1.0 | - | 1.0 | μs |

Table 12. Dynamic characteristics for temperature range -40°C to $+125^{\circ}\text{C}$ ^[1] ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 5](#); for waveforms, see [Figure 3](#) and [Figure 4](#).

| Symbol | Parameter | Conditions | V _{CC(B)} | | | | | | | | Unit |
|-------------------|-----------------|---|--------------------|-----|---------------|-----|---------------|------|---------------|-----|--------|
| | | | 1.8 V ± 0.15 V | | 2.5 V ± 0.2 V | | 3.3 V ± 0.3 V | | 5.0 V ± 0.5 V | | |
| | | | Min | Max | Min | Max | Min | Max | Min | Max | |
| t _{dis} | disable time | $\overline{\text{OE}}$ to A; no external load [2] | - | - | - | - | 1.0 | 9.5 | 1.0 | 9.5 | ns |
| | | $\overline{\text{OE}}$ to B; no external load [2] | - | - | - | - | 1.0 | 10.7 | 1.0 | 9.6 | ns |
| | | $\overline{\text{OE}}$ to A | - | - | - | - | - | 280 | - | 280 | ns |
| | | $\overline{\text{OE}}$ to B | - | - | - | - | - | 220 | - | 220 | ns |
| t _t | transition time | port A | - | - | - | - | 0.7 | 4.5 | 0.7 | 4.5 | ns |
| | | port B | - | - | - | - | 0.5 | 4.1 | 0.4 | 4.7 | ns |
| t _W | pulse width | data inputs | - | - | - | - | 10 | - | 10 | - | ns |
| f _{data} | data rate | | - | - | - | - | - | 100 | - | 100 | Mbit/s |

- [1] t_{pd} is the same as t_{PLH} and t_{PHL} .
 t_{en} is the same as t_{PZL} and t_{PZH} .
 t_{dis} is the same as t_{PLZ} and t_{PHZ} .
 t_t is the same as t_{THL} and t_{TLH} .

- [2] Delay between $\overline{\text{OE}}$ going HIGH and when the outputs are disabled.

Table 13. Typical power dissipation capacitance table^{[1][2]}

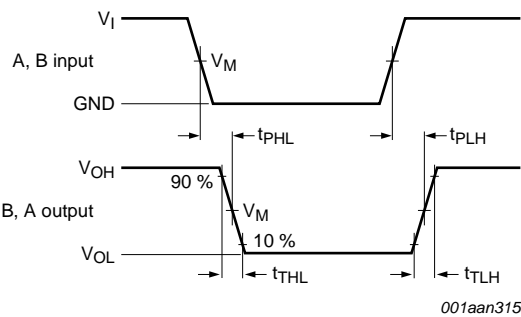
Tested at $T_{\text{amb}} = 25^{\circ}\text{C}$; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | V _{CC(A)} | | | | | | | Unit |
|-----------------|-------------------------------|---|--------------------|-------|-------|-------|-------|-------|----------------|------|
| | | | 1.2 V | 1.2 V | 1.5 V | 1.8 V | 2.5 V | 2.5 V | 3.3 V | |
| | | | V _{CC(B)} | | | | | | | |
| | | | 1.8 V | 5.0 V | 1.8 V | 1.8 V | 2.5 V | 5.0 V | 3.3 V to 5.0 V | |
| C _{PD} | power dissipation capacitance | outputs enabled; $\overline{\text{OE}} = \text{GND}$ | | | | | | | | |
| | | port A: (direction A to B) | 5 | 5 | 5 | 5 | 5 | 5 | 5 | pF |
| | | port A: (direction B to A) | 8 | 8 | 8 | 8 | 8 | 8 | 8 | pF |
| | | port B: (direction A to B) | 18 | 18 | 18 | 18 | 18 | 18 | 18 | pF |
| | | port B: (direction B to A) | 13 | 16 | 12 | 12 | 12 | 12 | 13 | pF |
| | | outputs disabled; $\overline{\text{OE}} = V_{\text{CC(A)}}$ | | | | | | | | |
| | | port A: (direction A to B) | 0.12 | 0.12 | 0.04 | 0.05 | 0.08 | 0.08 | 0.07 | pF |
| | | port A: (direction B to A) | 0.01 | 0.01 | 0.01 | 0.01 | 0.01 | 0.01 | 0.01 | pF |
| | | port B: (direction A to B) | 0.01 | 0.01 | 0.01 | 0.01 | 0.01 | 0.01 | 0.01 | pF |
| | | port B: (direction B to A) | 0.07 | 0.09 | 0.07 | 0.07 | 0.05 | 0.09 | 0.09 | pF |

- [1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 $P_D = C_{\text{PD}} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz;
 f_o = output frequency in MHz;
 C_L = load capacitance in pF;
 V_{CC} = supply voltage in V;
 N = number of inputs switching;
 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

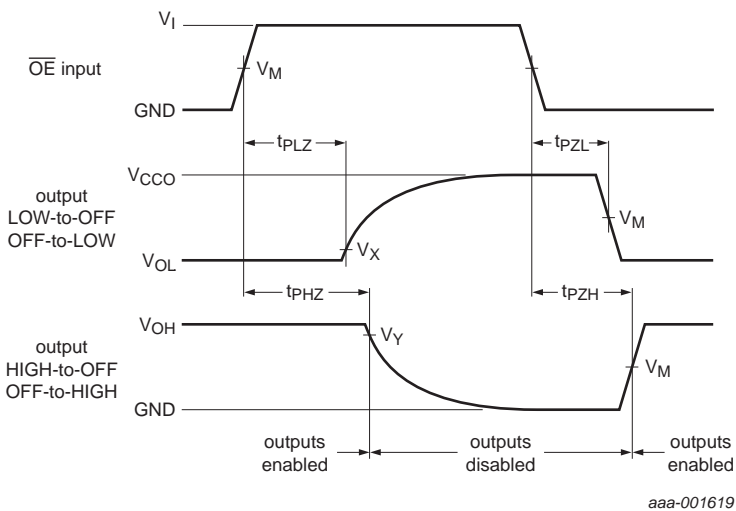
- [2] $f_i = 10\text{ MHz}$; $V_i = \text{GND to } V_{CC}$; $t_r = t_f = 1\text{ ns}$; $C_L = 0\text{ pF}$; $R_L = \infty\ \Omega$.

12. Waveforms



Measurement points are given in [Table 14](#).
 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 3. Data input (A, B) to data output (B, A) propagation delay times



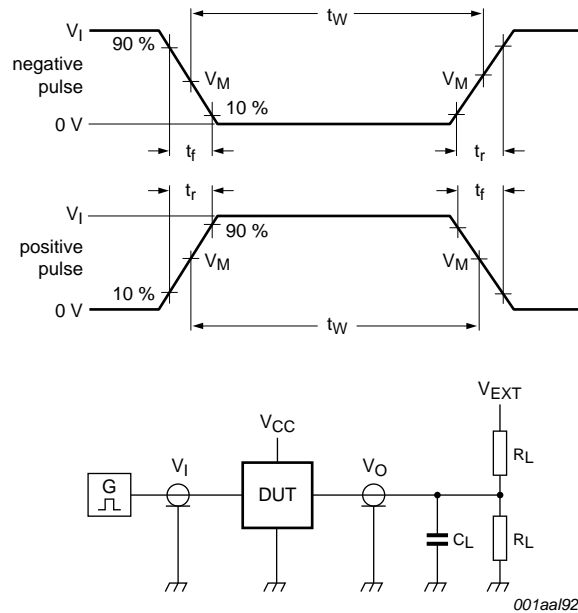
Measurement points are given in [Table 14](#).
 V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 4. Enable and disable times

Table 14. Measurement points^[1]

| Supply voltage | Input | Output | | |
|----------------------------------|--------------|--------------|--------------------------|--------------------------|
| | | V_M | V_X | V_Y |
| V_{CCO} | V_M | V_M | | |
| 1.2 V | $0.5V_{CCI}$ | $0.5V_{CCO}$ | $V_{OL} + 0.1\text{ V}$ | $V_{OH} - 0.1\text{ V}$ |
| $1.5\text{ V} \pm 0.1\text{ V}$ | $0.5V_{CCI}$ | $0.5V_{CCO}$ | $V_{OL} + 0.1\text{ V}$ | $V_{OH} - 0.1\text{ V}$ |
| $1.8\text{ V} \pm 0.15\text{ V}$ | $0.5V_{CCI}$ | $0.5V_{CCO}$ | $V_{OL} + 0.15\text{ V}$ | $V_{OH} - 0.15\text{ V}$ |
| $2.5\text{ V} \pm 0.2\text{ V}$ | $0.5V_{CCI}$ | $0.5V_{CCO}$ | $V_{OL} + 0.15\text{ V}$ | $V_{OH} - 0.15\text{ V}$ |
| $3.3\text{ V} \pm 0.3\text{ V}$ | $0.5V_{CCI}$ | $0.5V_{CCO}$ | $V_{OL} + 0.3\text{ V}$ | $V_{OH} - 0.3\text{ V}$ |
| $5.0\text{ V} \pm 0.5\text{ V}$ | $0.5V_{CCI}$ | $0.5V_{CCO}$ | $V_{OL} + 0.3\text{ V}$ | $V_{OH} - 0.3\text{ V}$ |

[1] V_{CCI} is the supply voltage associated with the input and V_{CCO} is the supply voltage associated with the output.



Test data is given in [Table 15](#).

All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$; $Z_O = 50 \Omega$; $dV/dt \geq 1.0 \text{ V/ns}$.

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

V_{EXT} = External voltage for measuring switching times.

Fig 5. Test circuit for measuring switching times

Table 15. Test data

| Supply voltage | | Input | | Load | | V_{EXT} | | |
|----------------|-----------------|----------------------|-------------------------|-------|------------------------------|-----------------------|-----------------------|--------------------------------------|
| $V_{CC(A)}$ | $V_{CC(B)}$ | V_I ^[1] | $\Delta t/\Delta V$ | C_L | R_L ^[2] | t_{PLH} , t_{PHL} | t_{PZH} , t_{PHZ} | t_{PZL} , t_{PLZ} ^[3] |
| 1.2 V to 3.6 V | 1.65 V to 5.5 V | V_{CCI} | $\leq 1.0 \text{ ns/V}$ | 15 pF | 50 k Ω , 1 M Ω | open | open | $2V_{CCO}$ |

[1] V_{CCI} is the supply voltage associated with the input.

[2] For measuring data rate, pulse width, propagation delay and output rise and fall measurements, $R_L = 1 \text{ M}\Omega$. For measuring enable and disable times, $R_L = 50 \text{ k}\Omega$.

[3] V_{CCO} is the supply voltage associated with the output.

13. Application information

13.1 Applications

Voltage level-translation applications. The NTB0101A can be used to interface between devices or systems operating at different supply voltages. See [Figure 6](#) for a typical operating circuit using the NTB0101A.

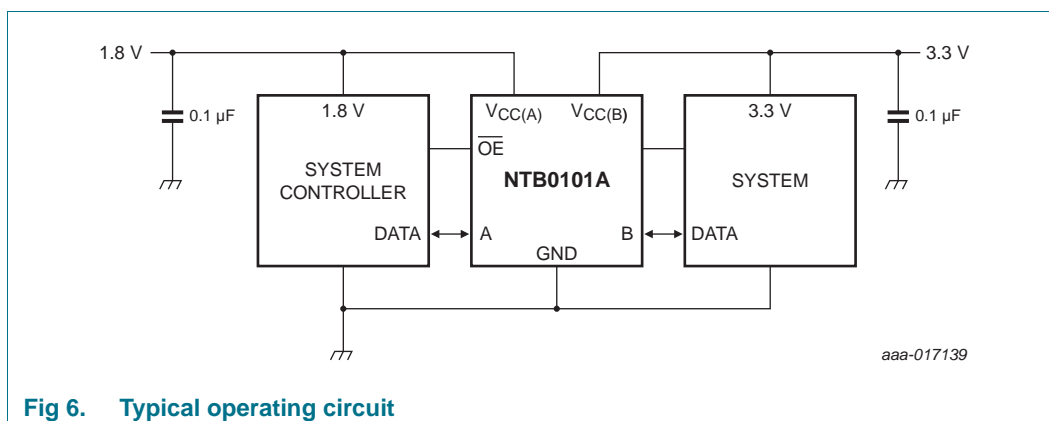


Fig 6. Typical operating circuit

13.2 Architecture

The architecture of the NTB0101A is shown in Figure 7. The device does not require an extra input signal to control the direction of data flow from A to B or from B to A. In a static state, the output drivers of the NTB0101A can maintain a defined output level, but the output architecture is weak, so that they can be overdriven by an external driver when data on the bus starts flowing in the opposite direction. The output of one-shot circuits detect rising or falling edges on the ports A or B. During a rising edge, the one-shot circuits turn on the PMOS transistors (T1, T3) for a short duration, accelerating the LOW-to-HIGH transition. Similarly, during a falling edge, the one-shot circuits turn on the NMOS transistors (T2, T4) for a short duration, accelerating the HIGH-to-LOW transition. During output transitions, the typical output impedance is $70\ \Omega$ at $V_{CCO} = 1.2\text{ V to }1.8\text{ V}$. It is $50\ \Omega$ at $V_{CCO} = 1.8\text{ V to }3.3\text{ V}$ and $40\ \Omega$ at $V_{CCO} = 3.3\text{ V to }5.0\text{ V}$.

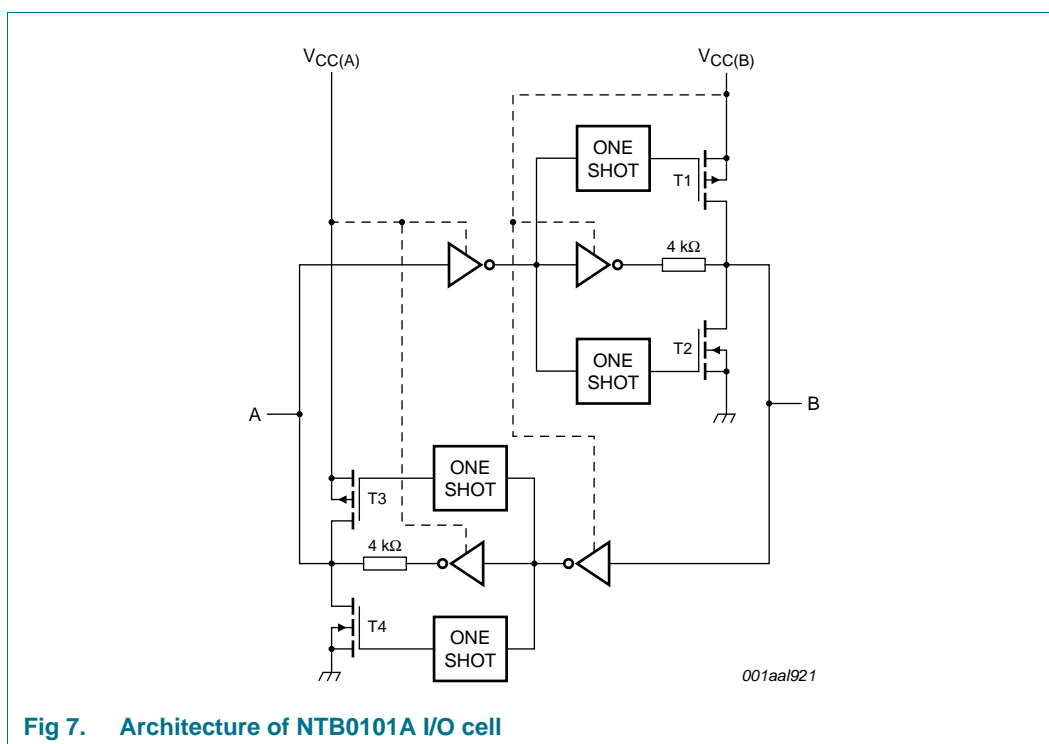
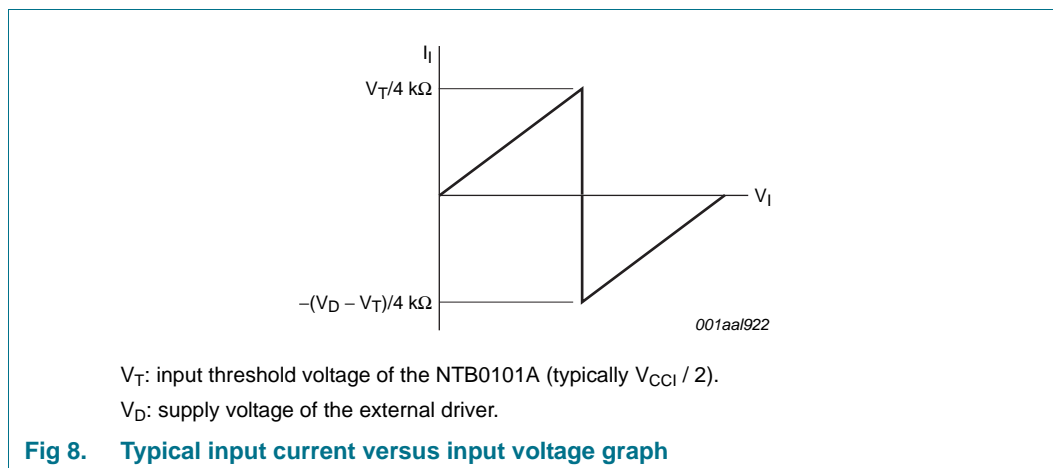


Fig 7. Architecture of NTB0101A I/O cell

13.3 Input driver requirements

For correct operation, the device that drives the data I/Os of the NTB0101A must have a minimum drive capability of ± 2 mA. See [Figure 8](#) for a plot of typical input current versus input voltage.



13.4 Power-up

$V_{CC(A)}$ must never be higher than $V_{CC(B)}$ during operation. However during power-up, $V_{CC(A)} \geq V_{CC(B)}$ does not damage the device. Either of the power supplies can be ramped up first and hence no special power-up sequencing is required. The NTB0101A includes circuitry that disables all output ports when either $V_{CC(A)}$ or $V_{CC(B)}$ is switched off.

13.5 Enable and disable

An output enable input (\overline{OE}) is used to disable the device. Setting $\overline{OE} = \text{HIGH}$ causes all I/Os to assume the high-impedance OFF-state. The disable time (t_{dis} with no external load) indicates the delay between when \overline{OE} goes HIGH and when outputs actually become disabled. The enable time (t_{en}) indicates the amount of time the user must allow for a one-shot circuitry to become operational after \overline{OE} is taken LOW. To ensure a high-impedance OFF-state during power-up or power-down, pin \overline{OE} should be tied to $V_{CC(A)}$ through a pull-up resistor. The minimum value of the resistor determines the current-sourcing capability of the driver.

13.6 Pull-up or pull-down resistors on I/O lines

As mentioned previously, the NTB0101A is designed with low static drive strength to drive capacitive loads of up to 70 pF. To avoid output contention issues, all pull-up or pull-down resistors used, must be above 50 kΩ. For this reason, NTB0101A is not recommended for use in open-drain driver applications such as 1-Wire or I²C-bus. For these applications, the NTS0101 level translator is recommended.

14. Package outline

Plastic surface-mounted package; 6 leads

SOT363

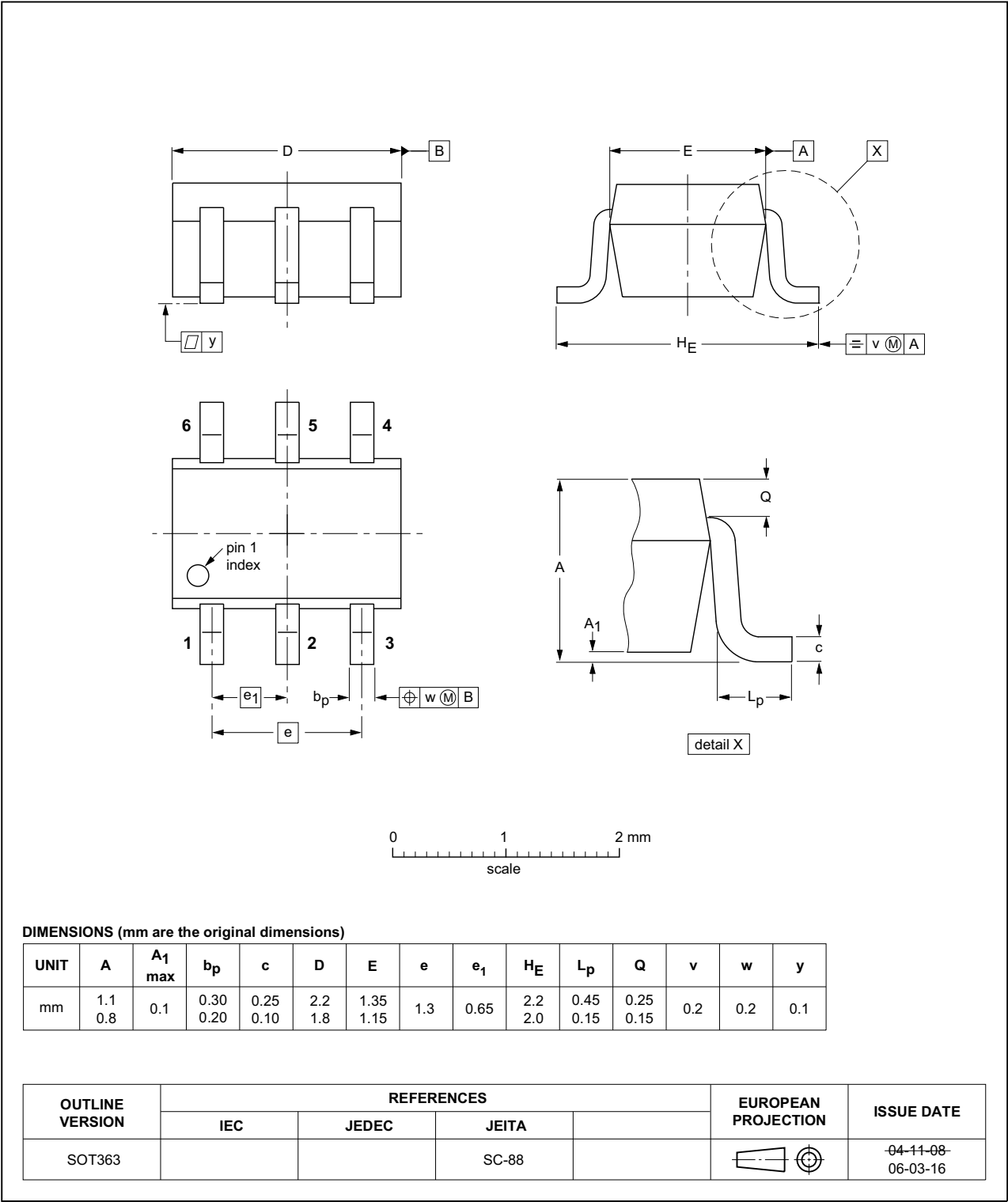


Fig 9. Package outline SOT363 (SC-88)

15. Abbreviations

Table 16. Abbreviations

| Acronym | Description |
|---------|----------------------------------|
| CDM | Charged Device Model |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |
| NMOS | N-type Metal Oxide Semiconductor |
| PMOS | P-type Metal Oxide Semiconductor |
| PRR | Pulse Repetition Rate |

16. Revision history

Table 17. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|--------------|--------------|--------------------|---------------|------------|
| NTB0101A v.1 | 20150714 | Product data sheet | - | - |

17. Legal information

17.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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